



# STTA6006P STTA12006TV1/2

## TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

### MAIN PRODUCT CHARACTERISTICS

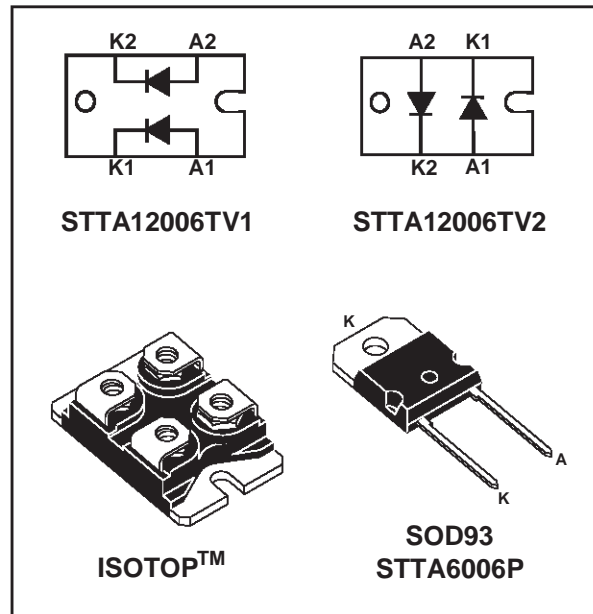
$I_{F(AV)}$	60A / 2 x 60A
$V_{RRM}$	600V
$t_{rr}$ (typ)	45ns
$V_F$ (max)	1.5V

### FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE.
- ULTRA-FAST RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY OPERATIONS.
- INSULATED PACKAGE: ISOTOP  
Electrical insulation : 2500V<sub>RMS</sub>  
Capacitance < 45 pF

### DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V. TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor



control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in ISOTOP or SOD93 these 600V devices are particularly intended for use on 240V domestic mains.

### ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		600	V
$V_{RSM}$	Non repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current	SOD93	80	A
		ISOTOP	150	A
$I_{FRM}$	Repetitive peak forward current	$t_p=5\mu s$ F=5kHz square	450	A
$I_{FSM}$	Surge non repetitive forward current	$t_p=10$ ms sinusoidal	500	A
$T_j$	Maximum operating junction temperature		150	°C
$T_{stg}$	Storage temperature range		-65 to 150	°C

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### THERMAL AND POWER DATA (Per diode)

Symbol	Parameter	Test conditions		Value	Unit
R <sub>th(j-c)</sub>	Junction to case thermal resistance	Per diode		0.85	°C/W
		Total		0.47	
		Coupling		0.1	
P <sub>1</sub>	Conduction power dissipation I <sub>F(AV)</sub> = 60A δ = 0.5	SOD93	T <sub>c</sub> = 64°C	108	W
		ISOTOP	T <sub>c</sub> = 58°C		
P <sub>max</sub>	Total power dissipation P <sub>max</sub> = P <sub>1</sub> + P <sub>3</sub> (P <sub>3</sub> = 10% P <sub>1</sub> )	SOD93	T <sub>c</sub> = 54°C	120	W
		ISOTOP	T <sub>c</sub> = 48°C		

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V <sub>F</sub> *	Forward voltage drop	I <sub>F</sub> = 60A	T <sub>j</sub> = 25°C T <sub>j</sub> = 125°C		1.25	1.75 1.5	V V
I <sub>R</sub> **	Reverse leakage current	V <sub>R</sub> = 0.8 x V <sub>R<sub>RM</sub></sub>	T <sub>j</sub> = 25°C T <sub>j</sub> = 125°C		5	200 12	μA mA
V <sub>to</sub>	Threshold voltage	I <sub>p</sub> < 3.I <sub>AV</sub>	T <sub>j</sub> = 125°C			1.14	V
r <sub>d</sub>	Dynamic resistance					6	mΩ

Test pulses : \* tp = 380 μs, δ < 2%

\*\* tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_F^2 (RMS)$$

### DYNAMIC ELECTRICAL CHARACTERISTICS

#### TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t <sub>rr</sub>	Reverse recovery time	T <sub>j</sub> = 25°C I <sub>F</sub> = 0.5 A I <sub>R</sub> = 1A I <sub>rr</sub> = 0.25A I <sub>F</sub> = 1 A dI <sub>F</sub> /dt = -50A/μs V <sub>R</sub> = 30V		45	80	ns
I <sub>RM</sub>	Maximum reverse recovery current	T <sub>j</sub> = 125°C V <sub>R</sub> = 400V I <sub>F</sub> = 60A dI <sub>F</sub> /dt = -480 A/μs dI <sub>F</sub> /dt = -500 A/μs		24	38	A
S factor	Softness factor	T <sub>j</sub> = 125°C V <sub>R</sub> = 400V I <sub>F</sub> = 60A dI <sub>F</sub> /dt = -500 A/μs		0.37		/

#### TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t <sub>fr</sub>	Forward recovery time	T <sub>j</sub> = 25°C I <sub>F</sub> = 60 A, dI <sub>F</sub> /dt = 480 A/μs measured at, 1.1 × V <sub>Fmax</sub>			700	ns
V <sub>Fp</sub>	Peak forward voltage	T <sub>j</sub> = 25°C I <sub>F</sub> = 60A, dI <sub>F</sub> /dt = 480 A/μs			14	V

Fig. 1: Conduction losses versus average current.

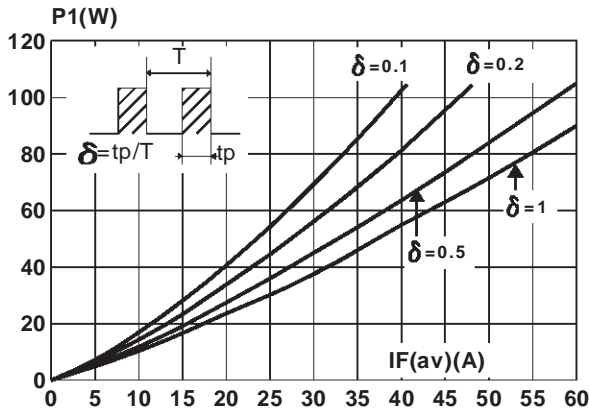


Fig. 2: Forward voltage drop versus forward current.

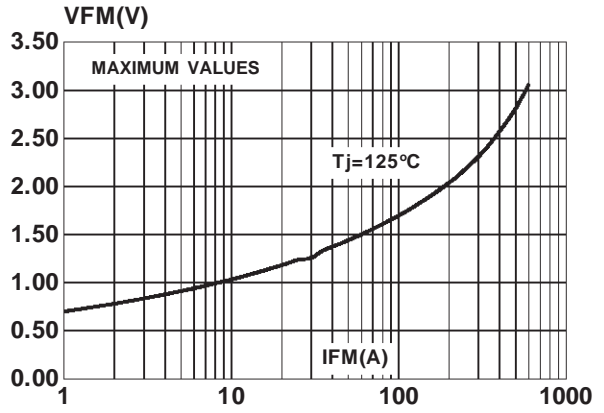


Fig. 3: Relative variation of thermal transient impedance junction to case versus pulse duration.

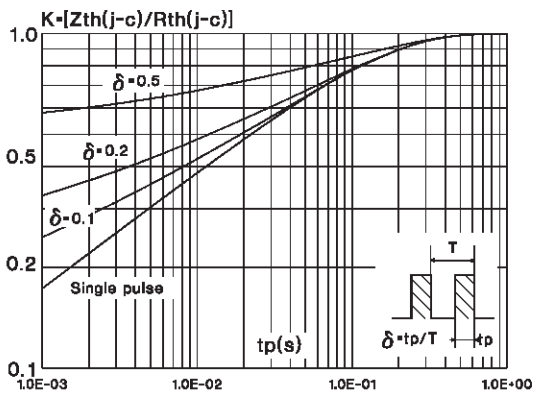


Fig. 4: Peak reverse recovery current versus dIF/dt.

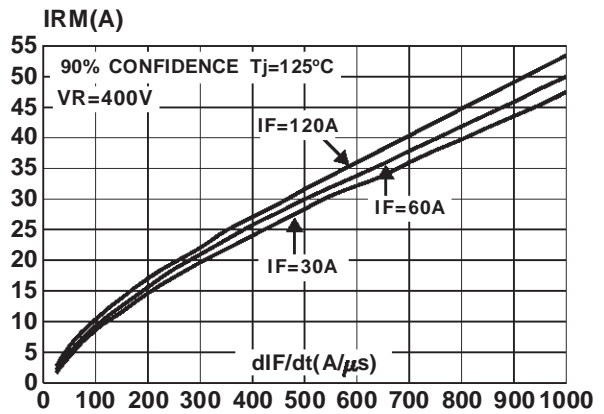


Fig. 5: Reverse recovery time versus dIF/dt.

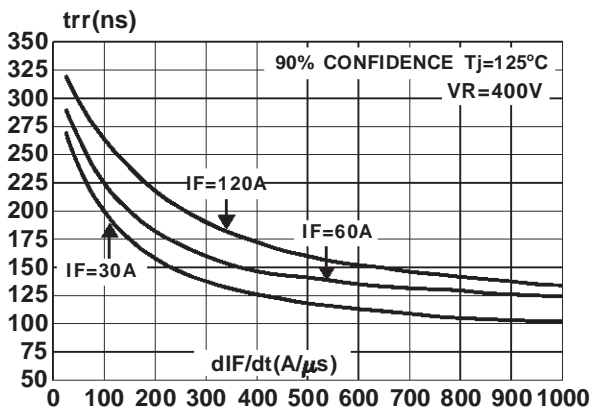


Fig. 6: Softness factor (tb/ta) versus dIF/dt.

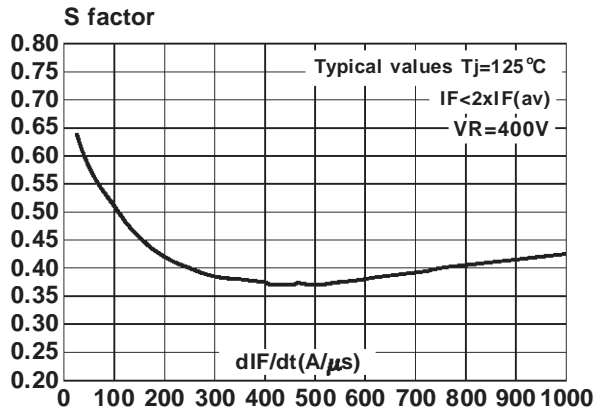


Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference  $T_j=125^\circ\text{C}$ ).

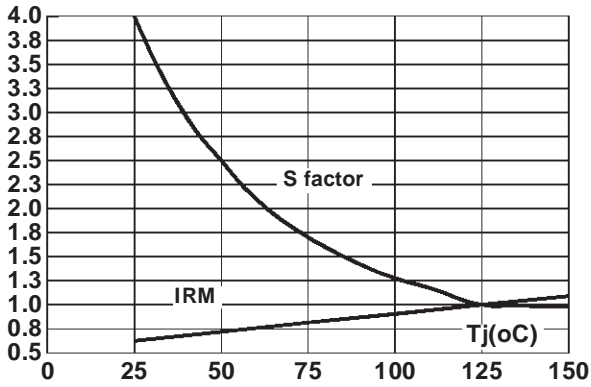


Fig. 8: Transient peak forward voltage versus  $dI_F/dt$ .

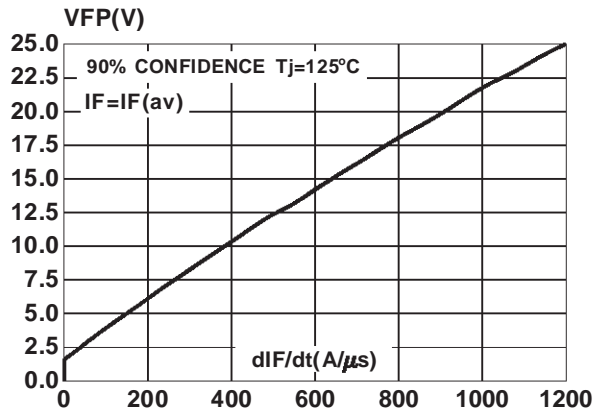
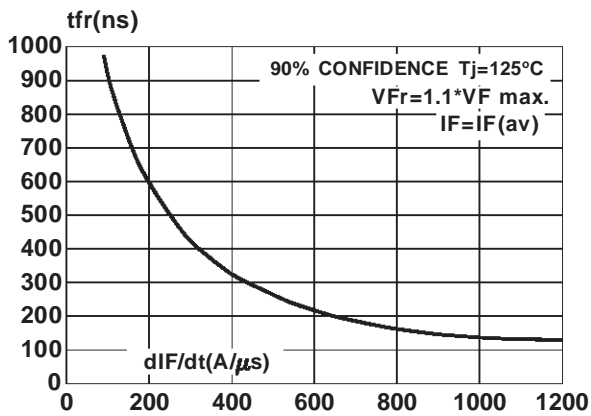


Fig. 9: Forward recovery time versus  $dI_F/dt$ .



**APPLICATION DATA**

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application. The way of calculating the power losses is given below:

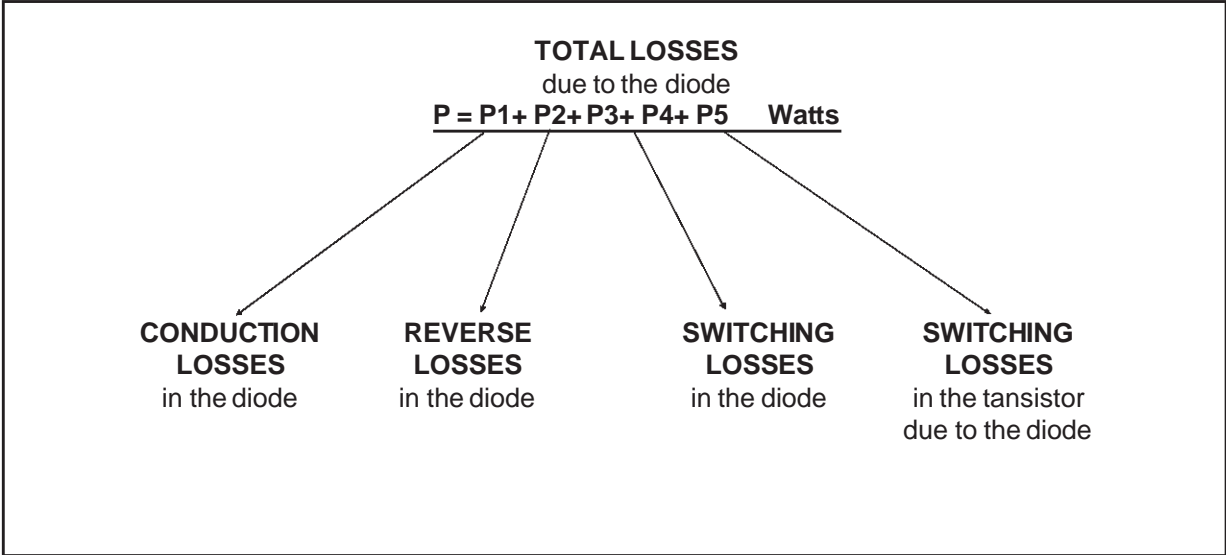
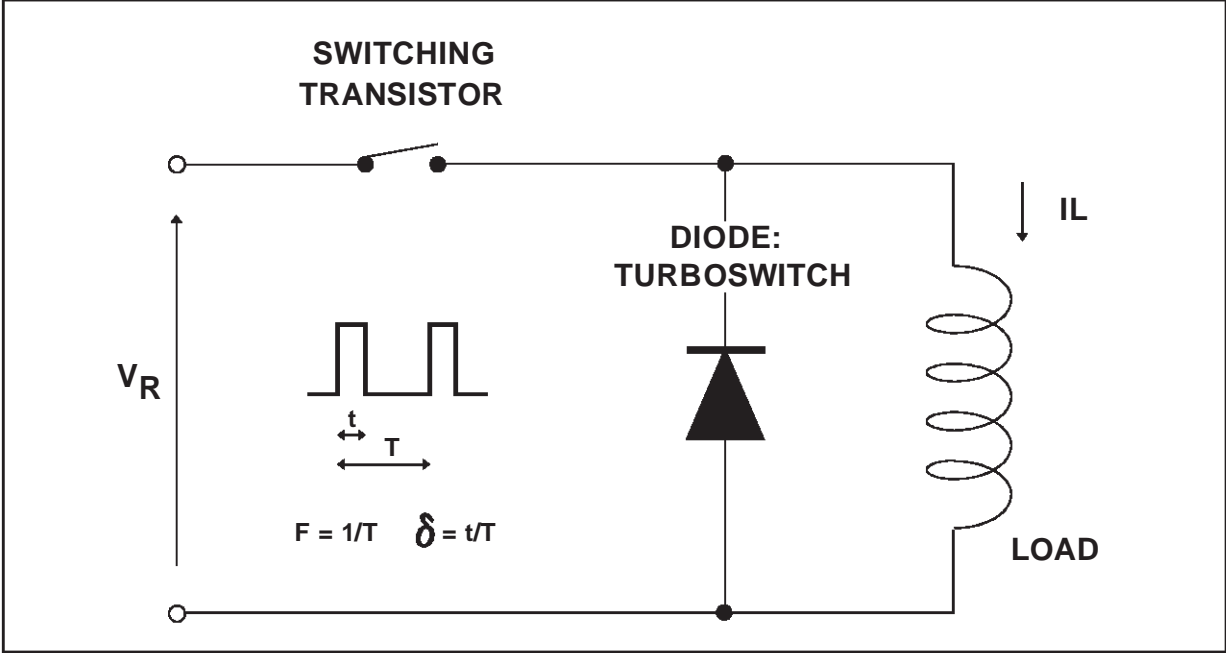
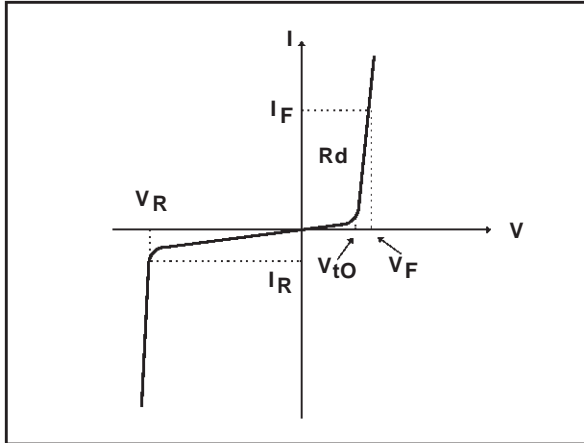


Fig. A : "FREEWHEEL" MODE.



APPLICATION DATA (Cont'd)

Fig. B: STATIC CHARACTERISTICS



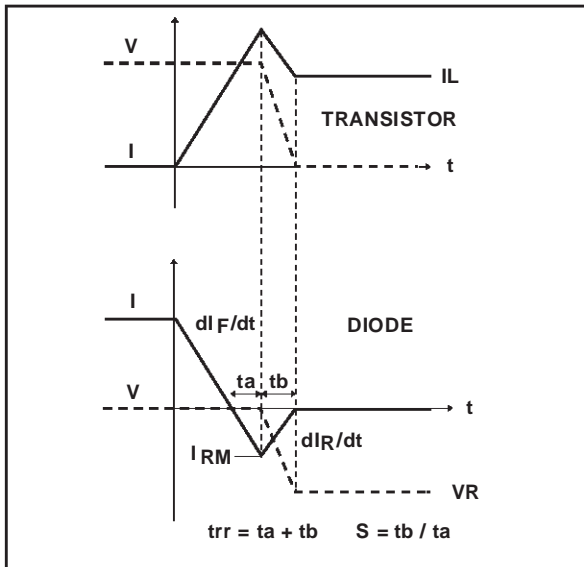
**Conduction losses :**

$$P1 = V_{t0} \cdot I_{F(AV)} + R_d \cdot I_{F(RMS)}^2$$

**Reverse losses :**

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C: TURN-OFF CHARACTERISTICS



**Turn-on losses :**

(in the transistor, due to the diode)

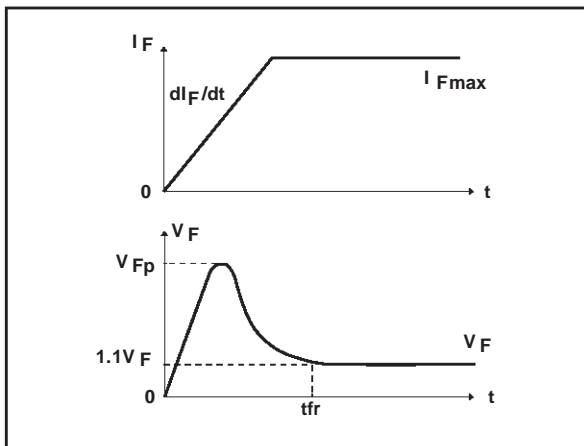
$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dl_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dl_F/dt}$$

**Turn-off losses (in the diode) :**

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dl_F/dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

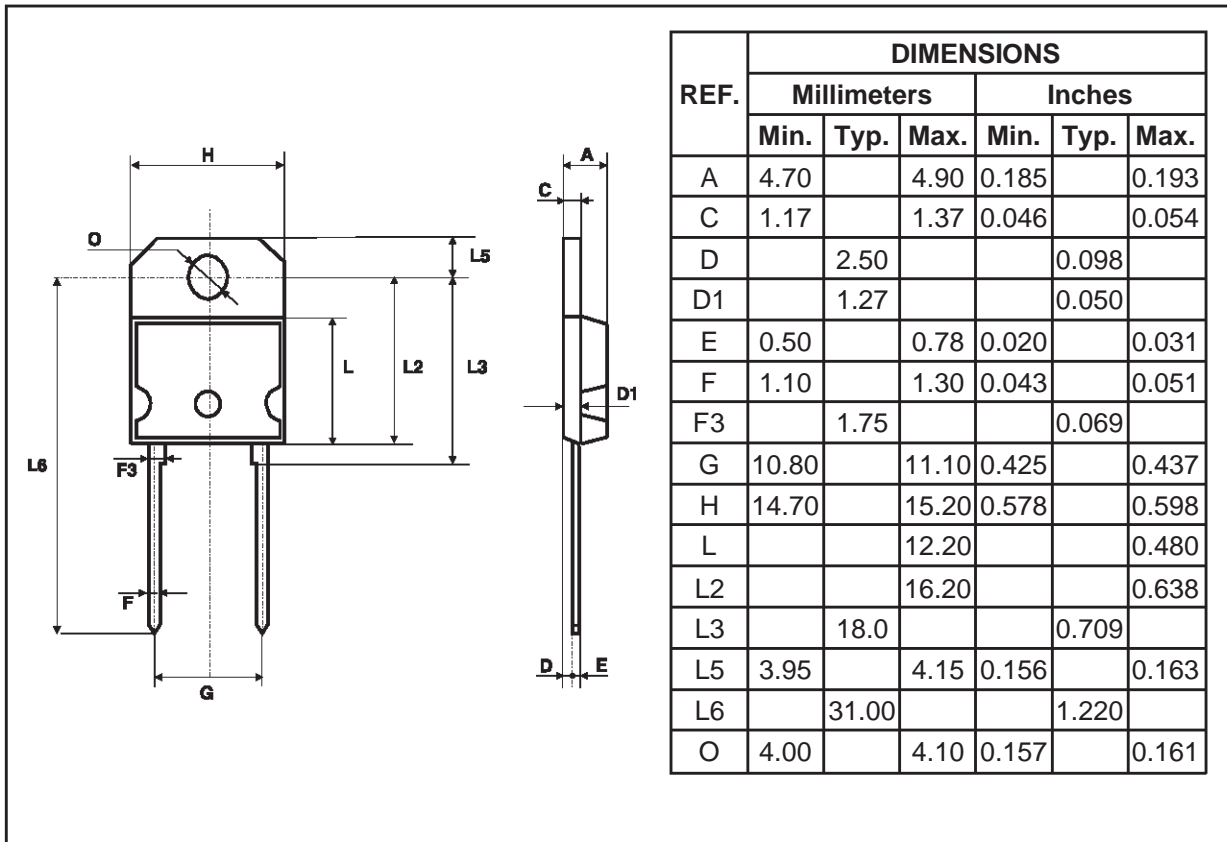
Fig. D: TURN-ON CHARACTERISTICS



**Turn-on losses :**

$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot F$$

**PACKAGE MECHANICAL DATA**  
SOD93



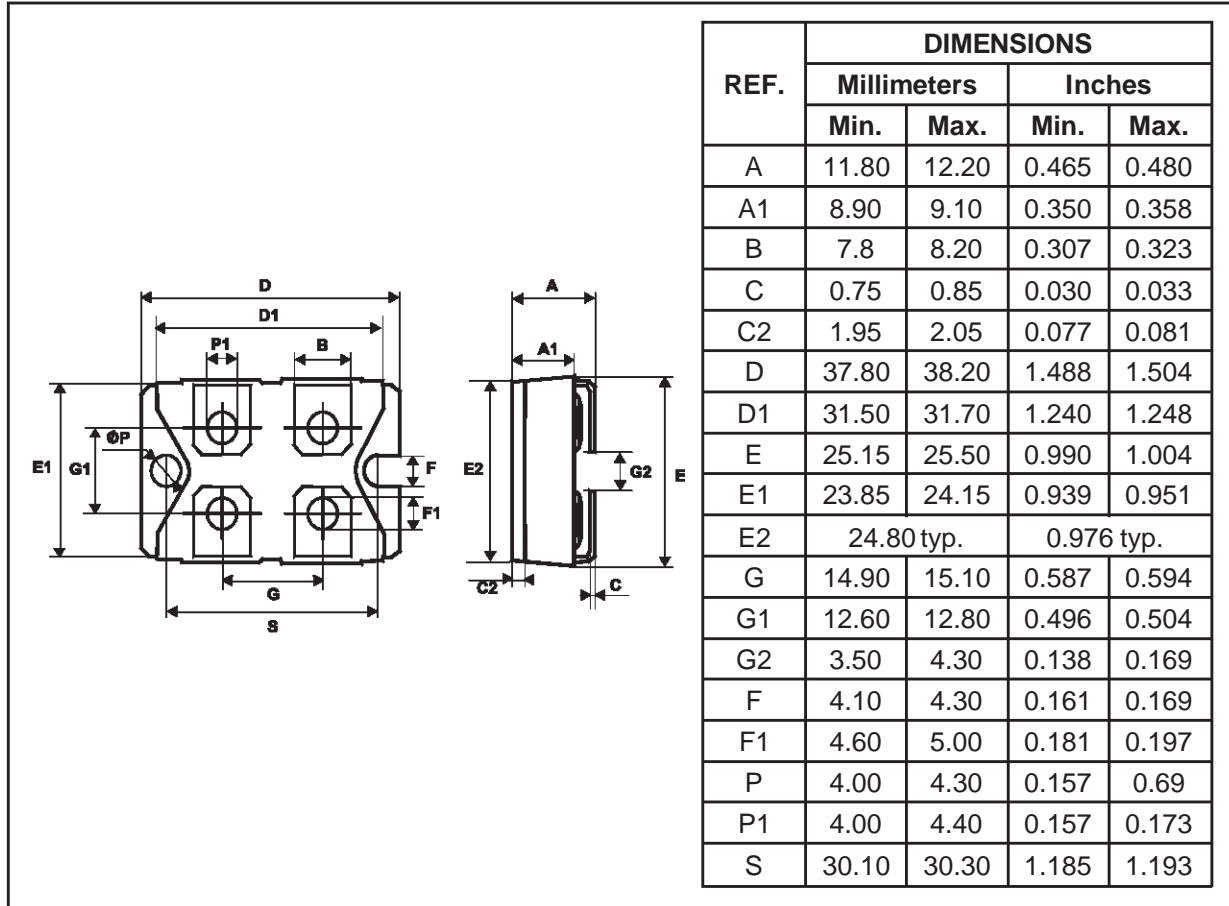
Cooling method : by conduction (C)

Recommended torque value : 0.8 m.N

Maximum torque value : 1m.N

**STTA12006TV1/2 / STTA6006P**

**PACKAGE MECHANICAL DATA**  
ISOTOP



Cooling method : by conduction (C)

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA6006P	STTA6006P	SOD93	3.79g	30	Tube
STTA12006TV1	STTA12006TV1	ISOTOP	27g without screws	10	Tube
STTA12006TV2	STTA12006TV2	ISOTOP		10	Tube

■ Epoxy meets UL94,V0

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